

FEATURES

- Rack mounted system
- Class AB linear LDMOS design
- Instantaneous wide bandwidth
- Suitable for all single channel modulation standards
- Built-in protection circuits
- High reliability and ruggedness



ELECTRICAL SPECIFICATIONS

Parameter	Specification	Notes
Operating Frequency Range	20 - 1000 MHz	
Power Output	300 Watt Min	CW
Power Gain	54 dB Min	
Power Gain Flatness	4.0 dB p-p Max	
Input Return Loss	10 dB Min	Relative to 50 Ohm
2-Tone Intermodulation (IMD)	-30 dBc Typ	44dBm/Tone, $\Delta = 1\text{MHz}$
Harmonics	-20 dBc Typ	
Spurious	-60dBc Max	Non-harmonic
Operating Voltage	180 - 240 VAC	
Power Consumption	2000 Watt Max	At rated Pout
Max Input Power Protection	+8 dBm	<10 Second without damage
Load VSWR Protection	$\infty : 1$	<1 Minute @ rated Pout

ENVIRONMENTAL CHARACTERISTICS

Parameter	Specification	Notes
Operating Ambient Temperature	0 to +50 °C	
Storage Temperature	-40 to +85 °C	
Relative Humidity	5 to 95 %	Non-condensation

MECHANICAL SPECIFICATIONS

Parameter	Specification	Notes
Dimensions W x H x D	430 x 133.3 x 560 mm	3U
Weight	20 Kg. Max	
RF Connectors In/Out	Type-N Female	Front Panel Standard
AC Power	IEC 60320-C14 / 9-Pin D-Sub	Or equivalent
Cooling	Built in Fan Cooling	Variable speed
OPTIONAL: Digital Monitor & Control FWD, REV, VSWR, GAIN, ALC, V & I, TEMP	Ethernet RJ-45 TCP/IP, RS422/485 Optional GPIB Interface	Remote Bluetooth application

OUTLINE DRAWING

